

HAC TEST REPORT

REPORT NO.: HA960621L09C

MODEL NO.: VOGU100

RECEIVED: Dec. 28, 2007

TESTED: Jan. 05 ~ Jan. 06, 2008

ISSUED: Jan. 10, 2008

APPLICANT: High Tech Computer Corp.

ADDRESS: 23, Hsin-Hua Rd., Taoyuan, 330, Taiwan, R.O.C.

ISSUED BY: Advance Data Technology Corporation

LAB ADDRESS: No. 47, 14th Ling, Chia Pau Tsuen, Lin Kou Hsiang

244, Taipei Hsien, Taiwan, R.O.C.

TEST LOCATION: No. 19, Hwa Ya 2nd Rd., Kwei Shan Hsiang, Taoyuan

Hsien 333, Taiwan, R.O.C.

This test report consists of 32 pages in total except Appendix. It may be duplicated completely for legal use with the approval of the applicant. It should not be reproduced except in full, without the written approval of our laboratory. The client should not use it to claim product endorsement by any government agencies. The test results in the report only apply to the tested sample.



TABLE OF CONTENTS

1.	CERTIFICATION	3
2.	GENERAL INFORMATION	4
2.1	GENERAL DESCRIPTION OF EUT	4
2.2	DESCRIPTIONOF SUPPORT UNITS	4
2.3	GENERAL DESCRIPTION OF APPLIED STANDARDS	7
3.	GENERAL INFORMATION OF THE DASY4 SYSTEM	8
3.1.	GENERAL INFORMATION OF TEST EQUIPMENT	8
3.2.	TEST EQUIPMENT LIST	12
3.3.	MEASUREMENT UNCERTAINTY	13
3.4.	GENERAL DESCRIPTION OF THE HAC EVALUATION	14
4.	PERFORMANCE CATEGORIES	16
5.	SYSTEM CHECK	18
5.1.	VALIDATION STRUCTURE	18
5.2.	SYSTEM CHECK PROCEDURE	19
5.3.	VALIDATION RESULTS	20
6.	MODULATION FACTOR	21
6.1	MODULATION FACTOR TEST RESULTS	23
7.	RF EMISSION TEST PROCEDURES	27
7.1.	TEST INSTRUCTION	27
7.2.	TEST PROCEDURES	28
7.3.	DESCRIPTION OF TEST POSITION AND CONFIGURATIONS	29
7.4.	SUMMARY OF MEASURED HAC RESULTS	30
8.	INFORMATION ON THE TESTING LABORATORIES	32
APP	ENDIX A: TEST CONFIGURATIONS AND TEST DATA	
APP	ENDIX B: ADT SAR MEASUREMENT SYSTEM	
APP	ENDIX C: PHOTOGRAPHS OF SYSTEM VALIDATION	
APP	ENDIX D: SYSTEM CERTIFICATE & CALIBRATION	
APP	ENDIX F: TEST CONFIGURATIONS	



1. CERTIFICATION

PRODUCT: Pocket PC phone

MODEL: VOGU100

APPLICANT: High Tech Computer Corp.

TESTED: Jan. 05 ~ Jan. 06, 2008

TEST SAMPLE: Engineering sample

STANDARDS: FCC Part 20.19

ANSI PC63.19: 2006

TEST ITEM: RF emissions

The above equipment (model: VOGU100) have been tested by Advance Data Technology Corporation, and found compliance with the requirement of the above standards. The test record, data evaluation & Equipment Under Test (EUT) configurations represented herein are true and accurate accounts of the measurements of the sample's EMC characteristics under the conditions specified in this report.

PREPARED BY : Zamie Sam , DATE: Jan. 10, 2008

Rennie Wang / Senior Specialist

TECHNICAL

ACCEPTANCE : Stanely 14--- , DATE: Jan. 10, 2008
Responsible for RF Stanely Hsu / Serior Engineer

APPROVED BY : Gary Chang / Supervisor , DATE: Jan. 10, 2008



2. GENERAL INFORMATION

2.1 GENERAL DESCRIPTION OF EUT

PRODUCT	Pocket PC phone			
MODEL NO.	VOGU100			
FCC ID	NM8VOGU100			
POWER SUPPLY	3.7Vdc from rechargeable lithium battery 5.0Vdc from power adapter 5.0Vdc from host equipment			
CLASSIFICATION	Portable	e device, production unit		
MODULATION TYPE	•	phone: OQPSK, HPSK th: GFSK for FHSS		
FREQUENCY RANGE	1850MH Bluetoo	z ~ 849MHz Hz ~ 1910MHz		
	SO55 RC3 TDSO SO32 RC3	0.296W (24.71dBm) / 836.5MHz for channel 384 0.279W (24.45dBm) / 848.3MHz for channel 777 CDMA850 band: 0.269W (24.29dBm) / 824.7MHz for channel 1013 0.283W (24.52dBm) / 836.5MHz for channel 384		
CHANNEL FREQUENCIES UNDER TEST AND	1xEVDO	O.265W (24.23dBm) / 848.3MHz for channel 777 CDMA850 band: 0.266W (24.25dBm) / 824.7MHz for channel 1013		
ITS CONDUCTED OUTPUT POWER	SO55 RC3	CDMA1900 band: 0.243W (23.86dBm) / 1851.25MHz for channel 25 0.256W (24.08dBm) / 1880.00MHz for channel 600 0.249W (23.96dBm) / 1908.75MHz for channel 1175		
	TDSO SO32 RC3	CDMA1900 band: 0.240W (23.81dBm) / 1851.25MHz for channel 25 0.248W (23.95dBm) / 1880.00MHz for channel 600 0.245W (23.89dBm) / 1908.75MHz for channel 1175		
	1xEVDO	CDMA1900 band: 0.209W (23.21dBm) / 1908.75MHz for channel 1175		
HAC RATE CATEGORY	M3			
ANTENNA TYPE	Mobile phone: Monopole antenna with 0dBi gain Bluetooth: PIFA antenna with 0dBi gain			



DATA CABLE	1.6m USB shielded cable without core
I/O PORTS	Refer to user's manual
ACCESSORY DEVICES	Refer to NOTE below

NOTE:

- 1. This report is issued as a supplementary report to the original ADT report no.: HA960621L09.
- 2. This report is prepared for FCC class II permissive change. The only difference is changing the CDMA PA. Therefore, test items for CDMA part had been re-tested.
- 3. The EUT is a CDMA2000 (850/1900) + 1xEVDO/ 1xRTT/ IS-95A/B Pocket PC phone with bluetooth V2.0 w EDR + AGPS functions.
- 4. The EUT has following accessories.

ACCESSORY	BRAND	MODEL	SUPPORTER	REMARKS
Belt Clip	HTC	PO S292	NEWTECH	
Carrying Case	HTC	PO S290	NEWTECH	
Earphone	HTC	HS S190	Merry	
Splitter (1)	нтс	YC A130	MEC	10.5cm (earphone with audio interface)
Splitter (2)	нтс	YC A100	Acon	9.7cm (earphone with USB interface)

5. The communicated functions of EUT listed as below:

		850MHz	1900MHz	
	CDMA	V	V	With bluetooth V2.0
3G	1xEVDO	V	V	w EDR + AGPS
	1xRTT	V	V	functions
	IS-95A/B	V	V	

6. The EUT has lithium batteries listed as below:

BATTERY A:		
BRAND:	TWS	
MODEL:	ELF0160	
RATING:	3.7Vdc, 1100mAh	

BATTERY B:			
BRAND:	SAMSUNG		
MODEL:	ELF0160		
RATING:	3.7Vdc, 1100mAh		

NOTE: After pre-tested both batteries, found battery A is worse, therefore all the test results came out from this.



7. The EUT was operated with following power adapters:

ADAPTER 1:	ADAPTER 1:			
BRAND:	DELTA ELECTRONIC, INC.			
MODEL:	ADP-5FH B			
INPUT:	100-240Vac, 0.2A, 50~60Hz			
OUTPUT:	5Vdc, 1A			
POWER LINE:	DC 1.8m non-shielded cable without core			

ADAPTER 2:	
BRAND:	htc
MODEL:	PSAA05A-050
INPUT:	100-240Vac, 200mA, 50-60Hz
OUTPUT:	5.0Vdc, 1A
POWER LINE:	DC 1.8m non-shielded cable without core

8. Refer to following table for ESN no.:

ESN NO.
36AD00**

9. The above EUT information was declared by manufacturer and for more detailed features description, please refer to the manufacturer's specifications or User's Manual.



2.2 DESCRIPTIONOF SUPPORT UNITS

The EUT has been tested as an independent unit together with other necessary accessories or support units. The following support units or accessories were used to form a representative test configuration during the tests.

NO.	PRODUCT	BRAND	MODEL NO.	SERIAL NO.	CALIBRATED UNTIL
1	UNIVERSAL RADIO COMMUNICATION TESTER	R&S	CMU200	104484	Jan. 24, 2008

NO.	SIGNAL CABLE DESCRIPTION OF THE ABOVE SUPPORT UNITS
1	NA

NOTE: All power cords of the above support units are non shielded (1.8m).

2.3 GENERAL DESCRIPTION OF APPLIED STANDARDS

According to the specifications of the manufacturer, this product must comply with the requirements of the following standards:

FCC Part 20.19

ANSI PC63.19: 2006

All test items have been performed and recorded as per the above standards.



3. GENERAL INFORMATION OF THE DASY4 SYSTEM

3.1. GENERAL INFORMATION OF TEST EQUIPMENT

DASY4 (software 4.7 Build 53) consists of high precision robot, probe alignment sensor, phantom, robot controller, controlled measurement server and near-field probe. The robot includes six axes that can move to the precision position of the DASY4 software defined. The DASY4 software can define the area that is detected by the probe. The robot is connected to controlled box. Controlled measurement server is connected to the controlled robot box. The DAE includes amplifier, signal multiplexing, AD converter, offset measurement and surface detection. It is connected to the Electro-optical coupler (ECO). The ECO performs the conversion form the optical into digital electric signal of the DAE and transfers data to the PC.

ER3DV6 E-FIELD PROBE

CONSTRUCTION One dipole parallel, two dipoles normal to probe axis Built-in shielding against

static charges

CALIBRATION In air from 100MHz to 3.0GHz (absolute accuracy ± 6.0%, k = 2)

FREQUENCY 100MHz to > 6GHz; Linearity: ± 0.2dB (100MHz to 3GHz)

DIRECTIVITY \pm 0.2dB in air (rotation around probe axis)

± 0.4dB in air (rotation normal to probe axis)

DYNAMIC RANGE 2V/m to > 1000V/m (M3 or better device readings fall well below diode

compression point) Linearity: ± 0.2dB

DIMENSIONS Overall length: 330mm (Tip: 16mm)

Tip diameter: 8mm (Body: 12mm)

Distance from probe tip to dipole centers: 2.5mm



H3DV6 H-FIELD PROBE

CONSTRUCTION Three concentric loop sensors with 3.8mm loop diameters Resistively loaded

detector diodes for linear response Built-in shielding against static charges

FREQUENCY 200MHz to 3GHz (absolute accuracy \pm 6.0%, k = 2); Output linearized

DIRECTIVITY ± 0.25dB (spherical isotropy error)

DYNAMIC RANGE 10mA/m to 2A/m at 1GHz (M3 or better device readings fall well below diode

compression point)

DIMENSIONS Overall length: 330mm (Tip: 40mm)

Tip diameter: 6mm (Body: 12mm)

Distance from probe tip to dipole centers: 3mm

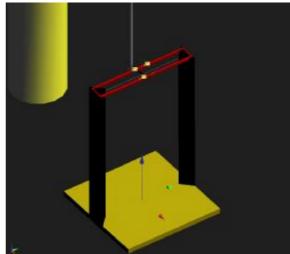
E-FIELD < 10% at 3GHz (for plane wave)

INTERFERENCE

NOTE: The Probe parameters have been calibrated by the SPEAG. Please reference "APPENDIX D" for the Calibration Certification Report.

HAC ARCH





DIMENSIONS 370 x 370 x 370mm



SYSTEM VALIDATION KITS:

Frequency Band: 800 ~ 960MHz (free space)

Return Loss: > 15dB

CD835V3 Calibrated at: 835MHz

Power Capability: 50W continuous Length & Height: 166 x 330mm

Frequency Band: 1710 ~ 2000MHz (free space)

Return Loss: > 18dB

CD1880V3 Calibrated at: 1880MHz

Power Capability: 50W continuous Length & Height: 80.8 x 330mm

Frequency Band: 2250 ~ 2650MHz (free space)

Return Loss: > 18dB

CD2450V3 Calibrated at: 2450MHz

Power Capability: 50W continuous Length & Height: 60 x 330mm



DEVICE HOLDER





CONSTRUCTION

Supports accurate and reliable positioning of any phone effect on near field <+/-0.5 dB



DATA ACQUISITION ELECTRONICS (DAE)



CONSTRUCTION

The data acquisition electronics (DAE3) consists of a highly sensitive electrometer grade preamplifier with auto-zeroing, a channel and gain-switching multiplex, a fast 16 bit AD converter and a command decoder and control logic unit. Transmission to the measurement server is accomplished through an optical downlink for data and status information as well as an optical uplink for commands and the clock. The mechanical probe is mounting device includes two different sensor systems for frontal and sideways probe contacts. They are used for mechanical surface detection and probe collision detection. The input impedance of the DAE3 box is 200MOhm; the inputs are symmetrical and floating. Common mode rejection is above 80dB.

Reference No.: 961228L01



3.2. TEST EQUIPMENT LIST

ITEM	NAME	BAND TYPE		SERIES NO.	CALIBRATED UNTIL
1	SAM Phantom	S&P	SD HAC P01 BA	1034	NA
2	Robot Positioner Staubli NA NA		NA	NA	
3	Signal Generator Anritsu 68247B 98470		984703	May 18, 2008	
4	E-Field Probe	Speag	ER3DV6	2293	Jan. 22, 2008
5	H-Field Probe	Speag	H3DV6	6124	Jan. 22, 2008
6	DAE	Speag	DAE	579	Mar. 22, 2008
7	Validation Dipole	Speag	CD835V3	1041	May 21, 2008
,	validation Dipole	Opeag	CD1880V3	1032	Jul. 17, 2008

NOTE: Before starting the measurement, all test equipment shall be warmed up for 30min.



3.3. MEASUREMENT UNCERTAINTY

	HAC UNCERTAINTY BUDGET ACCORDING TO ANSI C63.19[1]										
ERROR DESCRIPTION	UNCERTAINTY VALUE	PROBABILITY DISTRIBUTION	DIVISOR	(Ci)E	(Ci) H	STD. UNC. E	STD. UNC. H				
Probe calibration	±5.1%	Normal	1	1	1	±5.1%	±5.1%				
Axial isotropy	±4.7%	Rectangular	√3	1	1	±2.7%	±2.7%				
Sensor Displacement	±16.5%	Rectangular	√3	1	0.145	±9.5%	±1.4%				
Boundary Effects	±2.4%	Rectangular	√3	1	1	±1.4%	±1.4%				
Linearity	±4.7%	Rectangular	√3	1	1	±2.7%	±2.7%				
Scaling to Peak Envelope Power	±2.0%	Rectangular	√3	1	1	±1.2%	±1.2%				
System Detection Limit	±1.0%	Rectangular	√3	1	1	±0.6%	±0.6%				
Readout Electronics	±0.3%	Rectangular	√3	1	1	±0.3%	±0.3%				
Response Time	±0.8%	Rectangular	√3	1	1	±0.5%	±0.5%				
Integration Time	±2.6%	Rectangular	√3	1	1	±1.5%	±1.5%				
RF Ambient Condition	±3.0%	Rectangular	√3	1	1	±1.7%	±1.7%				
RF Reflections	±12.0%	Rectangular	√3	1	1	±6.9%	±6.9%				
Probe Positioner	±1.2%	Rectangular	√3	1	0.67	±0.7%	±0.5%				
Probe Positioning	±4.7%	Rectangular	√3	1	0.67	±2.7%	±1.8%				
Extrap. And Interpolation	±1.0%	Rectangular	√3	1	1	±0.6%	±0.6%				
		TEST SAMPLE REL	ATED								
Device Positioning Vertical	±4.7%	Rectangular	√3	1	0.67	±2.7%	±1.8%				
Device Positioning Lateral	±1.0%	Rectangular	√3	1	1	±0.6%	±0.6%				
Device Holder and Phantom	±2.4%	Rectangular	√3	1	1	±1.4%	±1.4%				
Power Drift	±5.0%	Rectangular	√3	1	1	±2.9%	±2.9%				
	PHA	NTOM AND SETUP	RELATED								
Phantom Thickness	±2.4%	Rectangular	√3	1	0.67	±1.4%	±0.9%				
	COMBINED S	TD. UNCERTAINTY				±14.7%	±10.9%				
E	XPANDED STD. UI	NCERTAINTY ON P	OWER			±29.4%	±21.8%				
	EXPANDED STD. U	INCERTAINTY ON F	FIELD			±14.7%	±10.9%				

NOTE: Worst-case uncertainty budget for HAC free field assessment according to ANSI C63.19 [1]. The budget is valid for the frequency range 800MHz ~ 3GHz and represents a worst-case analysis. For specific tests and configurations, the uncertainty could be considerably smaller.



3.4. GENERAL DESCRIPTION OF THE HAC EVALUATION

The DASY4 post-processing software (SEMCAD) automatically executes the following procedures to calculate the field units from the micro-volt readings at the probe connector. The parameters used in the evaluation are stored in the configuration modules of the software:

Probe parameters: - Sensitivity Norm_i, a_{i0}, a_{i1}, a_{i2}

The first step of the evaluation is a linearization of the filtered input signal to account for the compression characteristics of the detector diode. The compensation depends on the input signal, the diode type and the DC-transmission factor from the diode to the evaluation electronics. If the exciting field is pulsed, the crest factor of the signal must be known to correctly compensate for peak power. The formula for each channel can be given as:

$$V_i = U_i + U_i^2 \bullet \frac{cf}{dcp_i}$$

 V_i = compensated signal of channel i (i = x, y, z)

 U_i = input signal of channel I (i = x, y, z)

Cf = crest factor of exciting field (DASY parameter)

dcp_i = diode compression point (DASY parameter)



From the compensated input signals the primary field data for each channel can be evaluated:

E-field probes:
$$E_i = \sqrt{\frac{V_1}{Norm_i \cdot ConvF}}$$

H-field probes:
$$H_i = \sqrt{V_i} \cdot \frac{a_{i0} + a_{i1}f + a_{i2}f^2}{f}$$

 V_i = compensated signal of channel I (i = x, y, z)

Norm_i = sensor sensitivity of channel i $\mu V/(V/m)$ 2 for E-field Probes (i = x, y, z)

ConvF = sensitivity enhancement in solution

a_{ij} = sensor sensitivity factors for H-field probes

F = carrier frequency [GHz]

E_i = electric field strength of channel i in V/m

H_i = magnetic field strength of channel i in A/m

The RSS value of the field components gives the total field strength (Hermitian magnitude):

$$E_{tot} = \sqrt{E_x^2 + E_y^2 + E_z^2}$$

The primary field data are used to calculate the derived field units.

E = field strength in V/m

 E_{tot} = total field strength in V/m

NOTE: The signal response time is evaluated as the time required by the system to reach 90% of the expected final value after an on/off switch of the power source with an integration time of 500ms and a probe response time of < 5ms. In the current implementation, DASY4 waits longer than 100ms after having reached the grid point before starting a measurement, i.e., the response time uncertainty is negligible.



4. PERFORMANCE CATEGORIES

The ANSI Standard presents performance requirements for acceptable interoperability of hearing aids with wireless communications devices. When these parameters are met, a hearing aid operates acceptably in close proximity to a wireless communications device.

CATEGORY NEAR FIELD		TELEPHONE RF PARAMETERS < 960MHz									
	AWF	E-FIELD EMISSION CW (dBV/m)	E-FIELD EMISSION CW (V/m)	H-FIELD EMISSION CW (dBA/m)	H-FIELD EMISSION CW (A/m)						
M1	0	56.0 to 61.0	631.0 to 1122.0	5.6 to 10.6	1.91 to 3.39						
IVI I	-5	53.5 to 58.5	473.2 to 841.4	3.1 to 8.1	1.43 to 2.54						
M2	0	51.0 to 56.0	354.8 to 631.0	0.6 to 5.6	1.07 to 1.91						
IVIZ	-5	48.5 to 53.5	266.1 to 473.2	-1.9 to 3.1	0.80 to 1.43						
M3	0	46.0 to 51.0	199.5 to 354.8	-4.4 to 0.6	0.60 to 1.07						
WO	-5	43.5 to 48.5	149.6 to 266.1	-6.9 to -1.9	0.45 to 0.80						
M4	0	< 46.0	< 199.5	< -4.4	< 0.60						
1117	-5	< 43.5	< 149.6	< -6.9	< 0.45						

CATEGORY NEAR FIELD		TELEPHONE RF PARAMETERS > 960MHz									
	AWF	E-FIELD EMISSION CW (dBV/m)	E-FIELD EMISSION CW (V/m)	H-FIELD EMISSION CW (dBA/m)	H-FIELD EMISSION CW (A/m)						
M1	0	46.0 to 51.0	199.5 to 354.8	-4.4 to 0.6	0.60 to 1.07						
IVII	-5	43.5 to 48.5	149.6 to 266.1	-6.9 to -1.9	0.45 to 0.80						
M2	0	41.0 to 46.0	112.2 to 199.5	-9.4 to -4.4	0.34 to 0.60						
IVIZ	-5	48.5 to 53.5	84.1 to 149.6	-11.9 to -6.9	0.25 to 0.45						
M3	0	36.0 to 41.0	63.1 to 112.2	-14.4 to -9.4	0.19 to 0.34						
WIS	-5	33.5 to 38.5	47.3 to 84.1	-16.9 to -11.9	0.14 to 0.25						
M4	0	< 36.0	< 63.1	< -14.4	< 0.19						
	-5	< 33.5	< 47.3	< -16.9	< 0.14						



ARTICULATION WEIGHING FACTOR (AWF)

The following AWF factors shall be used for the standard transmission protocols:

STANDARD	TECHNOLOGY	AWF (dB)		
TIA/EIA/IS-2000	CDMA	0		
TIA/EIA-136	TDMA (50Hz)	0		
iDENTM	TDMA (22 and 11Hz)	0		
J-STD-007	GSM (217)	-5		
T1/T1P1/3GPP	UMTS (WCDMA)	0		



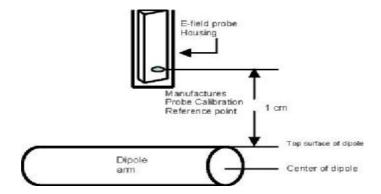
5. SYSTEM CHECK

The measured values (E-field and H-field) were compared with the values provided by the probe manufacturer and must within the allowed tolerance of **25%**.

5.1. VALIDATION STRUCTURE

The input signal was an un-modulated continuous wave. The following points were taken into consideration in performing this check:

- Average Input Power P = 100mW RMS (20dBm RMS) after adjustment for return loss
- The test fixture must meet the 2 wavelength separation criterion
- The proper measurement of the 1cm probe to dipole separation, which is measured from top surface of the dipole to the calibration reference point of the sensor, defined by the probe manufacturer is shown in the following diagram:

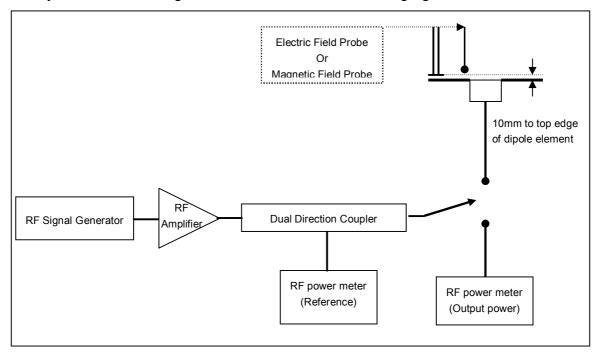




5.2. SYSTEM CHECK PROCEDURE

1. Before you start the system performance check, need only to tell the system with which components (probe type, validation dipole and HAC arch) are performing the system performance check; the system will take care of all parameters.

The system check configuration is shown in the following figure:



- 2. The dipole was energized with a 20dBm unmodulated continuous-wave signal.
- 3. The length of the dipole was scanned with both E-field and H-field probes and the maximum values for each were recorded.



5.3. VALIDATION RESULTS

	SYSTEM CHECK											
TEST FREQUENCY (MHz)	BEGIN TEST SG POWER (mW)	I REQUIRED I TO I DE		DEVIATION (%)	SEPARATION DISTANCE (mm)	TESTED DATE						
835	100.0	161.7	166.1	2.72	10	Jan. 06, 2008						
1880	100.0	137.4	129.6	-5.68	10	Jan. 05, 2008						
TEST FREQUENCY (MHz)	BEGIN TEST SG POWER (mW)	REQUIRED H-FILED (V/m)	MEASURED H-FILED (V/m)	DEVIATION (%)	SEPARATION DISTANCE (mm)	TESTED DATE						
835	100.0	0.457	0.470	2.84	10	Jan. 06, 2008						
1880	100.0	0.454	0.461	1.54	10	Jan. 05, 2008						
TESTED BY	Sam Onn											

NOTE: Please see Appendix for the system validation test data.



6. MODULATION FACTOR

A calibration was made of the modulation response of the probe and its instrumentation chain. This calibration was performed with the field probe, attached to its instrumentation. The response of the probe system to a CW field at the frequency of interest is compared to its response to a modulated signal with equal peak amplitude to that of a CW signal. The field level of the test signals are ensured to be more than 10dB above the ambient level and the noise floor of the instrumentation being used. The ratio of the CW reading to that taken with a modulated reading was applied to the DUT measurements.

This was done using the following procedure:

- 1. Fixing the probe in a set location relative to a field generating device, such as a reference dipole antenna, as illustrated in the system check procedure.
- 2. Illuminate the probe using the wireless device connected to the reference dipole with a test signal at the intended measurement frequency, Ensure there is sufficient field coupling between the probe and the antenna so the resulting reading is greater than 10dB above the probe system noise floor but within the systems operating range.
- 3. Record the amplitude applied to the antenna during transmission and the field strength measured by the E-field probe located near the tip of the dipole antenna.
- 4. Replace the wireless device with an RF signal generator producing an unmodulated CW signal and set to the wireless device operating frequency.
- 5. Set the amplitude of the unmodulated signal to equal that recorded from the wireless device.
- 6. Record the reading of the probe measurement system of the unmodulated signal.
- 7. The RF signal generator producing an 80%AM signal and set to the wireless device operating frequency. Set the amplitude of the signal to equal that recorded from the wireless device.



- 8. Record the reading of the probe measurement system of the 80%AM signal.
- 9. The ratio, in linear units, of the probe reading in Step 6) or 8) to the reading in Step 3) is the E-field modulation factor.
- 10. Steps 1-9 were repeated at all frequency bands and for both E and H field probes.

NOTE: The ratio of the CW to modulated signal reading is the modulation factor. The modulation factors obtained were applied to readings taken of the actual wireless device, in order to obtain an accurate peak field reading using the formula:

Peak = 20 · log(Raw · ProbeModulationFactor)



6.1 MODULATION FACTOR TEST RESULTS

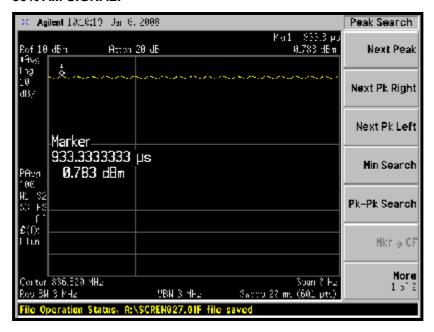
TEST FREQUENCY (MHz)	PROTOCOL	REFERENCE LEVEL	MEASURED E-FILED (V/m)	E-FILED MODULATION FACTOR	TESTED DATE	
	CW		177.5	NA		
836.5	80% AM	Refer to the next three plots	165.1	1.08	Jan. 06, 2008	
	CDMA		173.1	1.03		
TEST FREQUENCY (MHz)	PROTOCOL	REFERENCE LEVEL	MEASURED H-FILED (A/m)	H-FILED MODULATION FACTOR	TESTED DATE	
	CW		0.502	NA		
836.5	80% AM	Refer to the next three plots	0.469	1.07	Jan. 06, 2008	
	CDMA		0.491	1.02		
TESTED BY	Sam Onn					

CW SIGNAL:

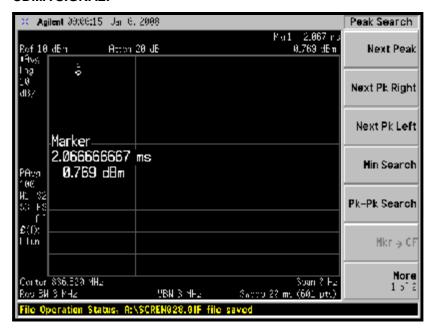




80% AM SIGNAL:



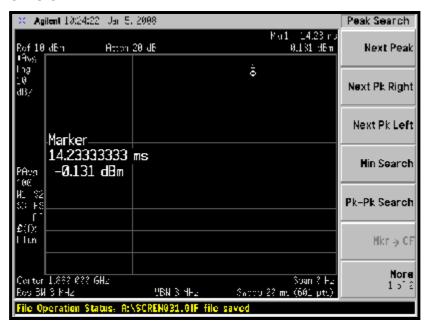
CDMA SIGNAL:





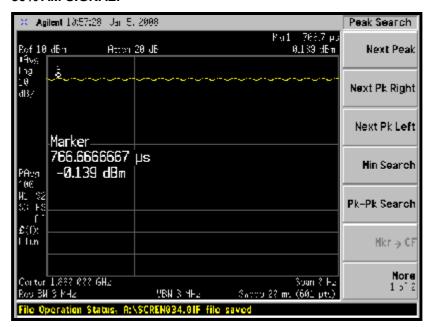
TEST FREQUENCY (MHz)	PROTOCOL	REFERENCE LEVEL	MEASURED E-FILED (V/m)	E-FILED MODULATION FACTOR	TESTED DATE		
	CW		127.7	NA			
1880.0	80% AM	Refer to the next three plots	120.3	1.06	Jan. 05, 2008		
	CDMA		122.7	1.04			
TEST FREQUENCY (MHz)	PROTOCOL	REFERENCE LEVEL	MEASURED H-FILED (A/m)	H-FILED MODULATION FACTOR	TESTED DATE		
	CW		0.451	NA			
1880.0	80% AM	Refer to the next three plots	0.417	1.08	Jan. 05, 2008		
	CDMA		0.430	1.05			
TESTED BY	Long Chen						

CW SIGNAL:





80% AM SIGNAL:



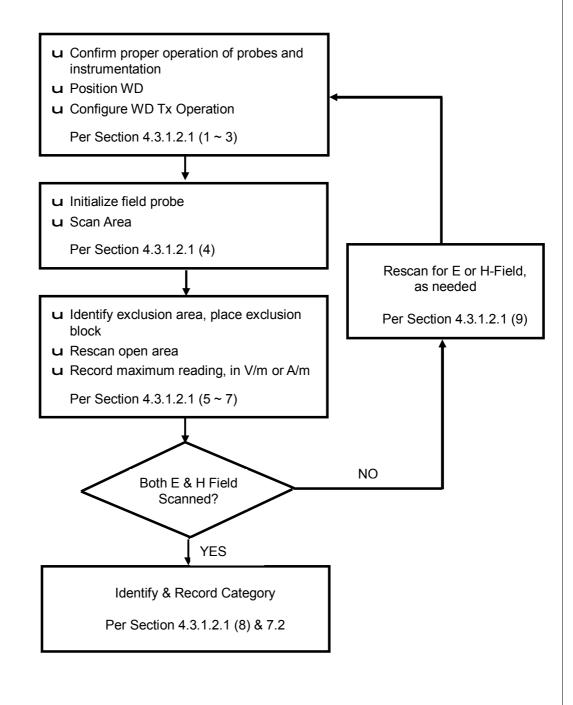
CDMA SIGNAL:





7. RF EMISSION TEST PROCEDURES

7.1. TEST INSTRUCTION





7.2. TEST PROCEDURES

The EUT makes a phone call to the GSM base station. Establish the simulation communication configuration rather the actual communication. Then the EUT could continuous the transmission mode. Adjust the PCL of the base station could controlled the EUT to transmitted the maximum output power. The base station also could control the transmission channel.

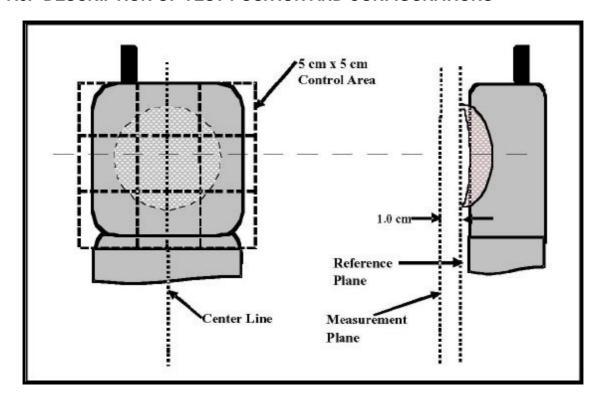
The recommended procedure for assessing the RF emission value consists of the following steps:

- 1. Proper operation of the field probe, probe measurement system, other instrumentation, and the positioning system was confirmed.
- 2. WD is positioned in its intended test position, acoustic output point of the device perpendicular to the field probe.
- 3. The center sub-grid was centered over the center of the acoustic output (also audio band magnetic output, if applicable). The WD audio output was positioned tangent (as physically possible) to the measurement plane.
- 4. A surface calibration was performed before each setup change to ensure repeatable spacing and proper maintenance of the measurement plane using the HAC arch.
- 5. The measurement system measured the field strength at the reference location.
- 6. Measurements at 2mm increments in the 5 x 5cm region were performed and recorded. A 360° rotation about the azimuth axis at the maximum interpolated position was measured. For the worst-case condition, the peak reading from this rotation was used in re-evaluating the HAC category.
- 7. Steps 1-6 were done for both the E and H-Field measurements.

•



7.3. DESCRIPTION OF TEST POSITION AND CONFIGURATIONS





7.4. SUMMARY OF MEASURED HAC RESULTS

E-FIELD EMISSION

ENVIRON CONDITIO				Air Temperature:22.1°C, Humidity:52%RH							
TESTED E	ЗҮ		Sam (Onn		DATE		Jan. 0	6, 2008		
FREQ. (MHz)	CHAN.	М	ODE	CONDUCTED POWER (dBm)	DRIFT (dB)	MEASURED PMF	_	LUDED ELLS	PEAK FIELD (V/m)	RATING	
824.70 (Low)	1013			24.44	-0.100		2,	3, 6	133.3	M4	
836.50 (Mid.)	384	CDI	MA850	24.71	-0.005	1.03	2,	3, 6	114.7	M4	
848.30 (High)	777			24.45	-0.038		2,	3, 6	117.1	M4	
824.70 (Low)	1013		MA850 ttery B)	24.44	-0.014	1.03	1.03 2,		132.0	M4	
824.70 (Low)	1013		MA850 ght off)	24.44	-0.060	1.03	2,	3, 6	130.7	M4	

ENVIRON CONDITIO			Air Temperature:22.1°C, Humidity:52%RH								
TESTED E	ЗҮ	San	Onn		DATE	Jan. 0	5, 2008				
FREQ. (MHz)	CHAN.	MODE	CONDUCTED POWER (dBm)	DRIFT (dB)	MEASURED PMF	EXCLUDED CELLS	PEAK FIELD (V/m)	RATING			
1851.25 (Low)	25		23.86	-0.103		6, 8, 9	68.8	M3			
1880.00 (Mid.)	600	CDMA19	24.08	-0.118	1.04	6, 8, 9	69.5	M3			
1908.75 (High)	1175		23.96	-0.086		6, 8, 9	70.6	M3			
1908.75 (High)	1175	CDMA19 (Battery E	23.96	-0.092	1.04	6, 8, 9	69.0	М3			
1908.75 (High)	1175	CDMA19	23 96	-0.065	1.04	6, 8, 9	66.2	M3			

NOTE:

- 1. The LCD back-light "ON" & battery A are the worst case for measurement.
- 2. Please see the Appendix A for the measured data and test plots.
- 3. The variation of the EUT conducted power measured before and after HAC testing should not over 5%.



H-FIELD EMISSION

ENVIRON CONDITIO				Air Temperature:22.1°C, Humidity:52%RH							
TESTED E	3Y		Sam (Onn		DATE		Jan. 0	6, 2008		
FREQ. (MHz)	CHAN.	М	ODE	CONDUCTED POWER (dBm)	DRIFT (dB)	MEASURED PMF	_	_	PEAK FIELD (A/m)	RATING	
824.70 (Low)	1013			24.44	-0.001		4,	7, 8	0.468	M4	
836.50 (Mid.)	384	CDI	MA850	24.71	-0.041	1.02	4,	7, 8	0.404	M4	
848.30 (High)	777			24.45	-0.005		4,	7, 8	0.410	M4	
824.70 (Low)	1013	CDMA850 (Battery B)		24.44	-0.113	1.02	4,	7, 8	0.462	M4	
824.70 (Low)	1013		MA850 jht off)	24.44	-0.039	1.02	4,	7, 8	0.458	M4	

ENVIRON CONDITIO			Air Temperature:22.1°C, Humidity:52%RH							
TESTED E	ЗҮ		Sam (Onn		DATE		Jan. 0	5, 2008	
FREQ. (MHz)	CHAN.	AN. M		CONDUCTED POWER (dBm)	DRIFT (dB)	MEASURED PMF	_	LUDED ELLS	PEAK FIELD (A/m)	RATING
1851.25 (Low)	25			23.86	-0.318		6,	8, 9	0.149	M4
1880.00 (Mid.)	600	CDM	1A1900	24.08	-0.086	1.05	6,	8, 9	0.164	M4
1908.75 (High)	1175			23.96	-0.319		6,	8, 9	0.214	МЗ
1908.75 (High)	1175	CDMA1900 (Battery B)		23.96	-0.216	1.05	6,	8, 9	0.211	М3
1908.75 (High)	1175		1A1900 ht off)	23.96	-0.330	1.05	6,	8, 9	0.208	МЗ

NOTE:

- 1. The LCD back-light "ON" & battery A are the worst case for measurement.
- 2. Please see the Appendix A for the measured data and test plots.
- 3. The variation of the EUT conducted power measured before and after HAC testing should not over 5%.



8. INFORMATION ON THE TESTING LABORATORIES

We, ADT Corp., were founded in 1988 to provide our best service in EMC, Radio, Telecom and Safety consultation. Our laboratories are accredited and approved by the following approval agencies according to ISO/IEC 17025.

USA FCC, UL, A2LA

GERMANY TUV Rheinland

JAPAN VCCI

NORWAY NEMKO

CANADA INDUSTRY CANADA, CSA

R.O.C. TAF, BSMI, NCC

NETHERLANDS Telefication

SINGAPORE GOST-ASIA (MOU)
RUSSIA CERTIS (MOU)

Copies of accreditation certificates of our laboratories obtained from approval agencies can be downloaded from our web site:

<u>www.adt.com.tw/index.5/phtml</u>. If you have any comments, please feel free to contact us at the following:

Linko EMC/RF Lab:Hsin Chu EMC/RF Lab:Tel: 886-2-26052180Tel: 886-3-5935343Fax: 886-2-26051924Fax: 886-3-5935342

Hwa Ya EMC/RF/Safety/Telecom Lab:

Tel: 886-3-3183232 Fax: 886-3-3185050

Web Site: www.adt.com.tw

The address and road map of all our labs can be found in our web site also.